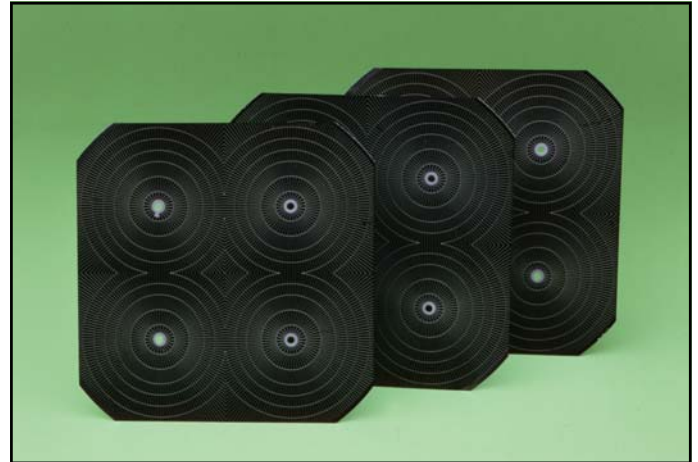


## Silicon K6700B Wrapthru Solar Cells

### Features

- High Conversion Efficiency
  - Beginning of Life and End of life
- High state-of-the-art reliability
- Optimized operating temperature
- Hardened applications
  - Space environmental effects: military and commercial
  - Terrestrial power
  - Consumer products
- Low Cost
  - Standard Products
  - Custom Products



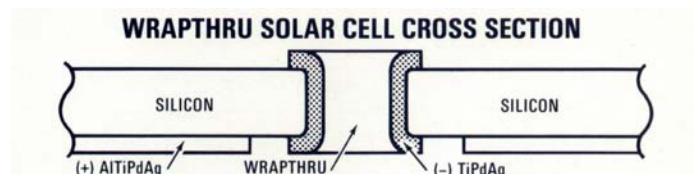
### Product Description

Standard/Special Product	Standard
Resistivity (p-type)	10 Ohm-cm
Crystal Orientation	1 - 0 - 0
Method of Growth	Czochralski
Shallow Junction	0.15 Micron
Metallization (Front)	TiPdAg Wrapthru
Metallization (Back)	AlTiPdAg Wrapthru
Anti-Reflective Coating	Multi-Layer
Back Surface Reflector	Gridded Back
Back Surface Field	Boron
Sculptured Front Surface	No
Thickness	200 Microns
Sizes	Up to 8x8 cm
Weldable	Yes
Solderable	Sn62 Solder (QQ-S-571)

Note: other variations are available upon request

### Typical Qualification Test Results Nominal Degradation

Test	Description	Results
Humidity	+45°C, 90% RH Min., 30 Days	<1.5%
Thermal Cycle	+80°C to -180°C, 3000 Cycles	<2.5%
Thermal Shock	+140°C to -185°C, 5 Cycles	<1.5%
Thermal Soak	+140°C for 168 Hrs., $5 \times 10^{-5}$ torr	<1.5%
Radiation	Characterized thru $5 \times 10^{14}$ 1 MeV e/cm <sup>2</sup>	—
Pull Test	90° Pull, Standard Tab	>250 gm



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The information contained on this sheet is for reference only. Specifications subject to change without notice. 01/17/2000

### Typical Electrical Parameters {AM0 Sunlight (135.3 mW/cm<sup>2</sup>), 28°C}

J<sub>sc</sub>= 41.9 MilliAmperes/cm<sup>2</sup>

J<sub>mp</sub>= 38.4 MilliAmperes/cm<sup>2</sup>

V<sub>mp</sub>= 0.500 Volts

P<sub>mp</sub>= 19.2 MilliWatts/cm<sup>2</sup>

V<sub>oc</sub>= 0.618 Volts

C<sub>ff</sub>= 0.74

Efficiency 14.2% Minimum Average

### Radiation Degradation (Fluence e/cm<sup>2</sup> 1 MeV Electrons)

Parameter	1x10 <sup>13</sup>	1x10 <sup>14</sup>	5x10 <sup>14</sup>
I <sub>sc</sub> /I <sub>sc0</sub>	0.99	0.94	0.85
I <sub>mp</sub> /I <sub>mp0</sub>	0.99	0.95	0.85
V <sub>mp</sub> /V <sub>mp0</sub>	0.95	0.88	0.82
V <sub>oc</sub> /V <sub>oc0</sub>	0.96	0.89	0.84
P <sub>mp</sub> /P <sub>mp0</sub>	0.94	0.84	0.70

### Thermal Properties

Solar Absorptance= 0.65 (CMX)

Solar Absorptance= 0.63 (Fused Silica)

Emittance (Normal)= 0.85 (CMX)

Emittance (Normal)= 0.81 (Fused Silica)

### Weight

55 Milligrams/ cm<sup>2</sup> (Bare)

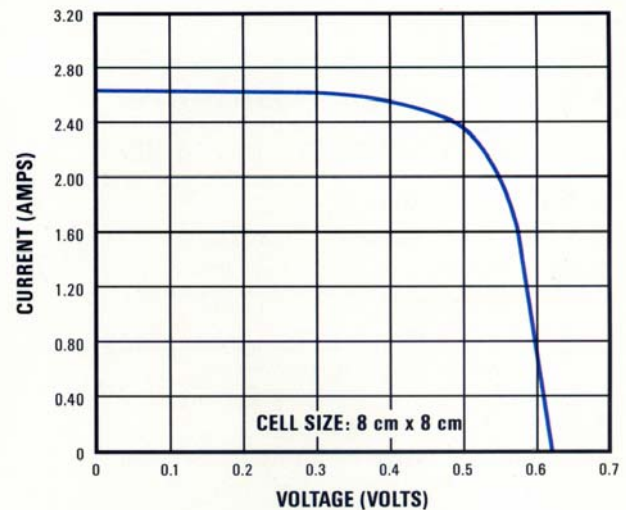
### Temperature Coefficients

I<sub>sc</sub>= +20.0 MicroAmperes/cm<sup>2</sup>

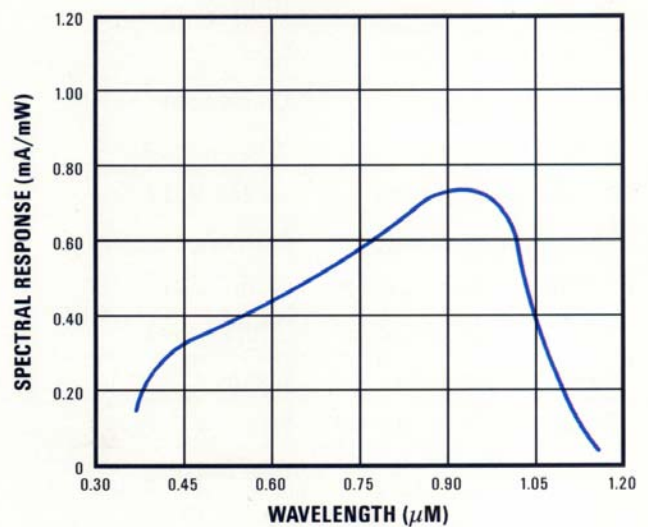
V<sub>mp</sub>= -2.15 MilliVolts/°C

V<sub>oc</sub>= -1.96 MilliVolts/°C

### Typical I-V Characteristic Curve AM0 Sunlight (135.3 mW/cm<sup>2</sup>), 28°C



### Spectral Response



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